

# CA3275

# **Dual Full Bridge Driver**

April 1994

### Features

- Two Full Bridge Drivers
- ± 150mA Maximum Current
- Logic Controlled Switching
- Direction Control
- PWM I<sub>OUT</sub> Control
- 18V Over-Voltage Protection
- 300mA Short-Circuit Protection
- Nominal 8V to 16V Operation
- Internal Voltage Regulation With Bandgap Reference

## Applications

- Dual Full Bridge Driver For Air Core Gauge Instrumentation
- µP Controlled Sensor Data Displays
- Speedometer Displays
- Tachometer Displays
- Stepper Motors
- Slave Position Indicators

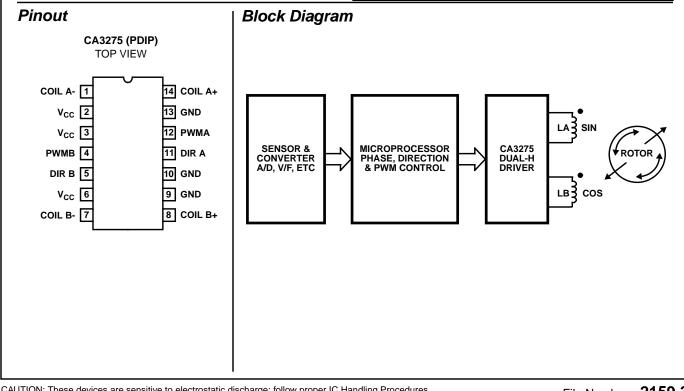
## Description

The CA3275 Dual Full Bridge Driver is intended for generalpurpose applications requiring Dual Full Bridge drive or switching, including direction and pulse-width modulation for position control. While all features of the IC may not be utilized or required, they would normally be used in instrumentation systems with quadrature coils, such as air-core gauges, where the coils would be driven at frequencies ranging from 200Hz to 400Hz. The coils are wrapped at 90° angles for independent direction control. Coils wound in this physical configuration are controlled by pulse width modulation, where each coil drive is a function of the sine or cosine versus degrees of movement. The direction control is used to change the direction of the current in the H-Driver coil.

The switch rate capability of the IC is typically 30kHz regardless of the inductive load. Over-current limiting is used to limit short circuit current. Over-voltage protection (in the range of 18V to 24V) causes the device to shut down the output current drive. Thermal shutdown limits power dissipation on the chip. The CA3275 is supplied in a 14 lead dual-inline plastic package.

## **Ordering Information**

PART NO.	TEMPERATURE	PACKAGE
CA3275E	-40°C to +85°C	14 Lead Plastic DIP



CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures. 1-888-INTERSIL or 321-724-7143 | Copyright © Intersil Corporation 1999

#### **Absolute Maximum Ratings**

#### **Thermal Information**

Operating V <sub>CC</sub> 16V   Transient V <sub>CC</sub> , 30 Seconds Maximum 24V   Peak V <sub>CC</sub> , 0.4 Seconds Maximum 40V   Maximum Continuous Output Current, ±100mA	PDIP Package
Each Drive	Above +70°C Derate Linearly at 10mW/°C
Maximum PWM Output Switching Current,	Ambient Temperature Range
Each Drive	Operating40°C to +85°C
	Storage55°C to +150°C
	Lead Temperature (During Soldering)+265°C
	At distance $1/16 \pm 1/32$ " (1.59 $\pm 0.79$ mm) from case for 10s max

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### **Electrical Specifications** $T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{CC} = 16V$ Unless Otherwise Specified

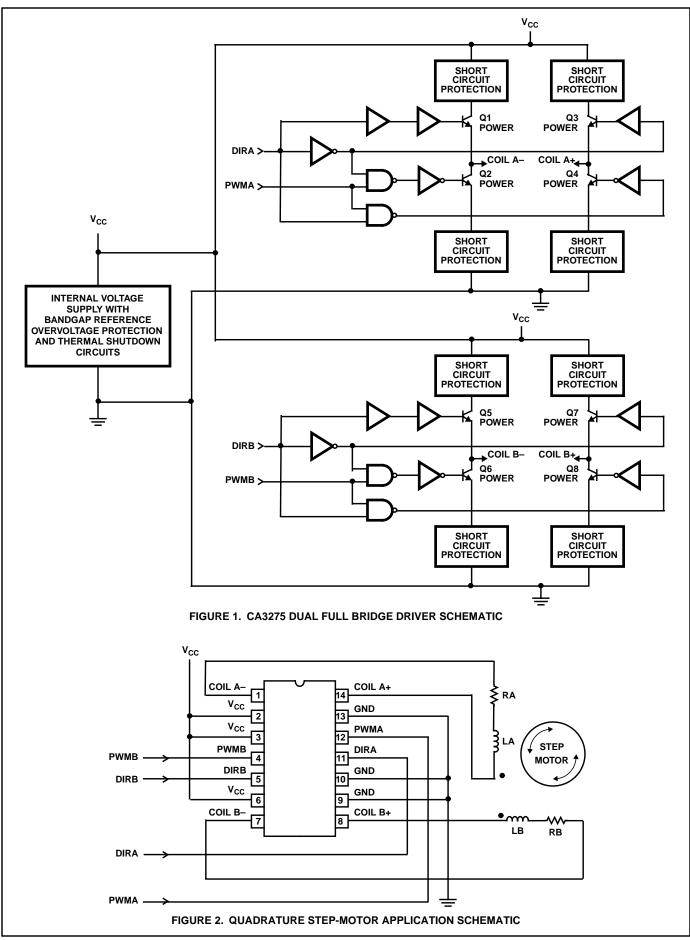
PARAMETERS	SYMBOL	MIN	ТҮР	МАХ	UNITS
Operating Supply Voltage Range	V <sub>CC</sub>	8	-	16	V
Supply Current (Note 1)	Icc	-	8	20	mA
INPUT LEVELS	•				
Logic Input, Low Voltage	VIL	-	-	0.8	V
Logic Input, High Voltage	V <sub>IH</sub>	3.5	-	-	V
Logic Input, Low Current, V <sub>IL</sub> = 0V	IIL	-10	-	-	μΑ
Logic Input, High Current, V <sub>IH</sub> = 5V	I <sub>IH</sub>	-	-	10	μΑ
OUTPUT: $RLA = RLB = 138\Omega$	•				
Maximum Source Saturated Voltage	V <sub>SAT</sub> - High	-	1.2	1.75	V
Maximum Sink Saturated Voltage	V <sub>SAT</sub> - Low	-	0.25	0.5	V
Differential V <sub>SAT</sub> Voltage, Both Outputs Saturated	Diff - V <sub>SAT</sub>	-	10	100	mV

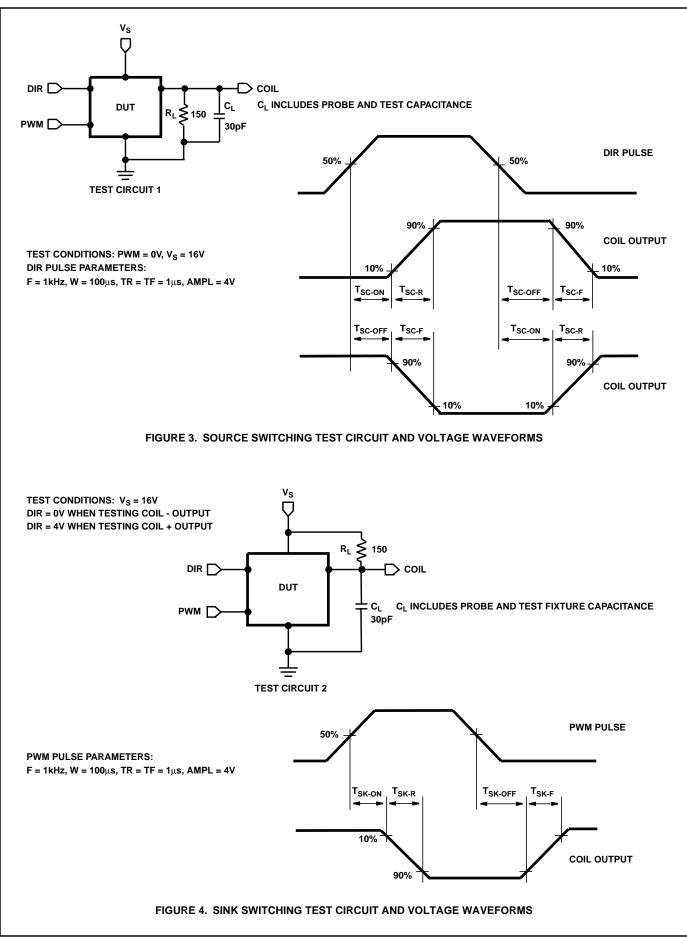
#### **Switching Specifications**

PARAMETERS	SYMBOL	MIN	ТҮР	MAX	UNITS
SOURCE CURRENT (See Figure 3)					
Turn-Off Delay	T <sub>SC-OFF</sub>	-	-	2	μs
Fall Time	T <sub>SC-F</sub>	-	-	2.2	μs
Turn-On Time	T <sub>SC-ON</sub>	-	-	1	μs
Rise Time	T <sub>SC-R</sub>	-	-	0.4	μs
SINK CURRENT (See Figure 4)	·				
Turn-Off Delay	T <sub>SK-OFF</sub>	-	-	1.6	μs
Fall Time	T <sub>SK-F</sub>	-	-	0.4	μs
Turn-On Time	T <sub>SK-ON</sub>	-	-	0.6	μs
Rise Time	T <sub>SK-R</sub>	-	-	0.2	μs

NOTE:

1. No load, PWMA = PWMB = 5V, DIR A = DIR B = 0V





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